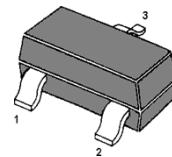


**MMBT2222A****TRANSISTOR (NPN)****FEATURES**

**Epitaxial planar die construction**

**Complementary PNP Type available(MMBT2222A)**

**MARKING: 1P**

**SOT-23**

1. BASE
2. Emitter
3. COLLECTOR

**MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

| Symbol                 | Parameter                               | Value     | Units |
|------------------------|---|-----------|-------|
| <b>V<sub>CBO</sub></b> | Collector-Base Voltage                  | 75        | V     |
| <b>V<sub>CEO</sub></b> | Collector-Emitter Voltage               | 40        | V     |
| <b>V<sub>EBO</sub></b> | Emitter-Base Voltage                    | 6         | V     |
| <b>I<sub>C</sub></b>   | Collector Current -Continuous           | 600       | mA    |
| <b>P<sub>C</sub></b>   | Collector Dissipation                   | 300       | mW    |
| <b>R<sub>0JA</sub></b> | Thermal Resistance, Junction to Ambient | 417       | °C/W  |
| <b>T<sub>J</sub></b>   | Junction Temperature                    | 150       | °C    |
| <b>T<sub>stg</sub></b> | Storage Temperature                     | -55to+150 | °C    |

**ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$  unless otherwise specified)**

| Parameter                                   | Symbol                 | Test conditions  | Min | Typ | Max        | Unit |
|---|------------------------|--|-----|-----|------------|------|
| <b>Collector-base breakdown voltage</b>     | $V_{(BR)CBO}$          | $I_C=10\mu\text{A}, I_E=0$   | 75  |     |            | V    |
| <b>Collector-emitter breakdown voltage</b>  | $V_{(BR)CEO}^*$        | $I_C= 10\text{mA}, I_B=0$  | 40  |     |            | V    |
| <b>Emitter-base breakdown voltage</b>       | $V_{(BR)EBO}$          | $I_E=10\mu\text{A}, I_C=0$   | 6   |     |            | V    |
| <b>Collector cut-off current</b>            | $I_{CBO}$              | $V_{CB}=60\text{V}, I_E=0$   |     |     | 0.01       | μA   |
| <b>Collector cut-off current</b>            | $I_{CEX}$              | $V_{CE}=30\text{V}, V_{BE(\text{off})}=3\text{V}$  |     |     | 0.01       | μA   |
| <b>Emitter cut-off current</b>              | $I_{EBO}$              | $V_{EB}=3\text{V}, I_C=0$  |     |     | 0.1        | μA   |
| <b>DC current gain</b>                      | $h_{FE(1)}^*$          | $V_{CE}=10\text{V}, I_C= 150\text{mA}$   | 100 |     | 300        |      |
|   | $h_{FE(2)}$            | $V_{CE}=10\text{V}, I_C= 0.1\text{mA}$   | 40  |     |            |      |
|   | $h_{FE(3)}^*$          | $V_{CE}=10\text{V}, I_C= 500\text{mA}$   | 42  |     |            |      |
| <b>Collector-emitter saturation voltage</b> | $V_{CE(\text{sat})}^*$ | $I_C=500 \text{ mA}, I_B= 50\text{mA}$<br>$I_C=150 \text{ mA}, I_B= 15\text{mA}$             |     |     | 1<br>0.3   | V    |
| <b>Base-emitter saturation voltage</b>      | $V_{BE(\text{sat})}^*$ | $I_C=500 \text{ mA}, I_B= 50\text{mA}$<br>$I_C=150 \text{ mA}, I_B= 15\text{mA}$             |     |     | 2.0<br>1.2 | V    |
| <b>Transition frequency</b>                 | $f_T$                  | $V_{CE}=20\text{V}, I_C= 20\text{mA},$<br>$f=100\text{MHz}$                                  | 300 |     |            | MHz  |
| <b>Delay time</b>                           | $t_d$                  | $V_{CC}=30\text{V}, V_{BE(\text{off})}=-0.5\text{V}$<br>$I_C=150\text{mA}, I_B= 15\text{mA}$ |     |     | 10         | nS   |
| <b>Rise time</b>                            | $t_r$                  |  |     |     | 25         | nS   |
| <b>Storage time</b>                         | $t_s$                  | $V_{CC}=30\text{V}, I_C=150\text{mA}$<br>$I_B1=-I_B2=15\text{mA}$                            |     |     | 225        | nS   |
| <b>Fall time</b>                            | $t_f$                  |  |     |     | 60         | nS   |

\*pulse test: Pulse Width ≤300μs, Duty Cycle≤ 2.0%.

## Typical Characteristics

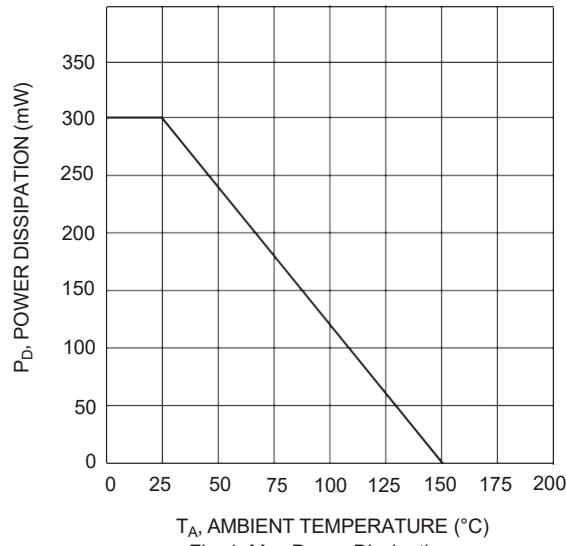


Fig. 1, Max Power Dissipation vs  
Ambient Temperature

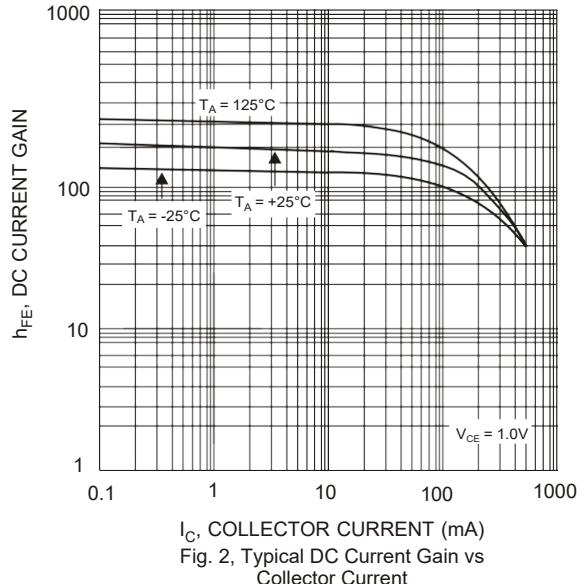


Fig. 2, Typical DC Current Gain vs  
Collector Current

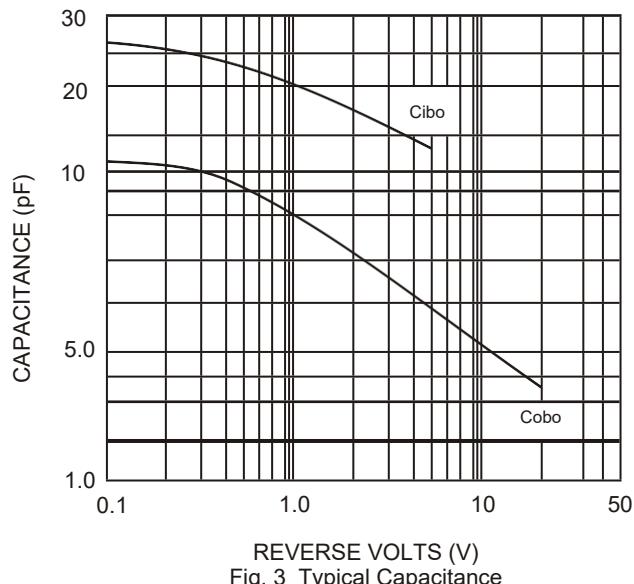


Fig. 3 Typical Capacitance

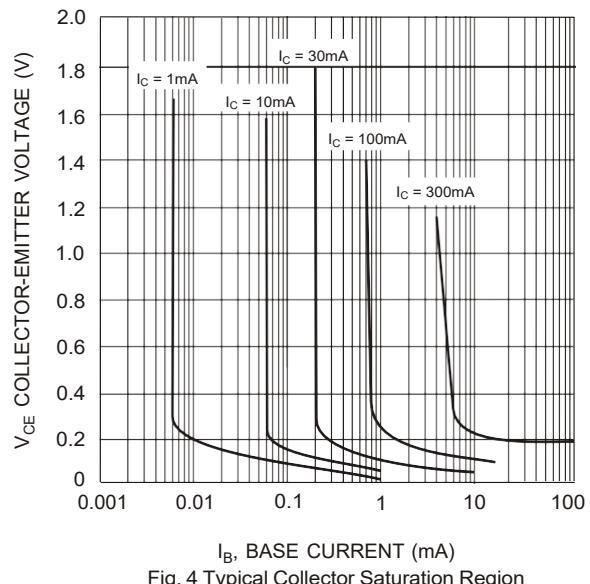
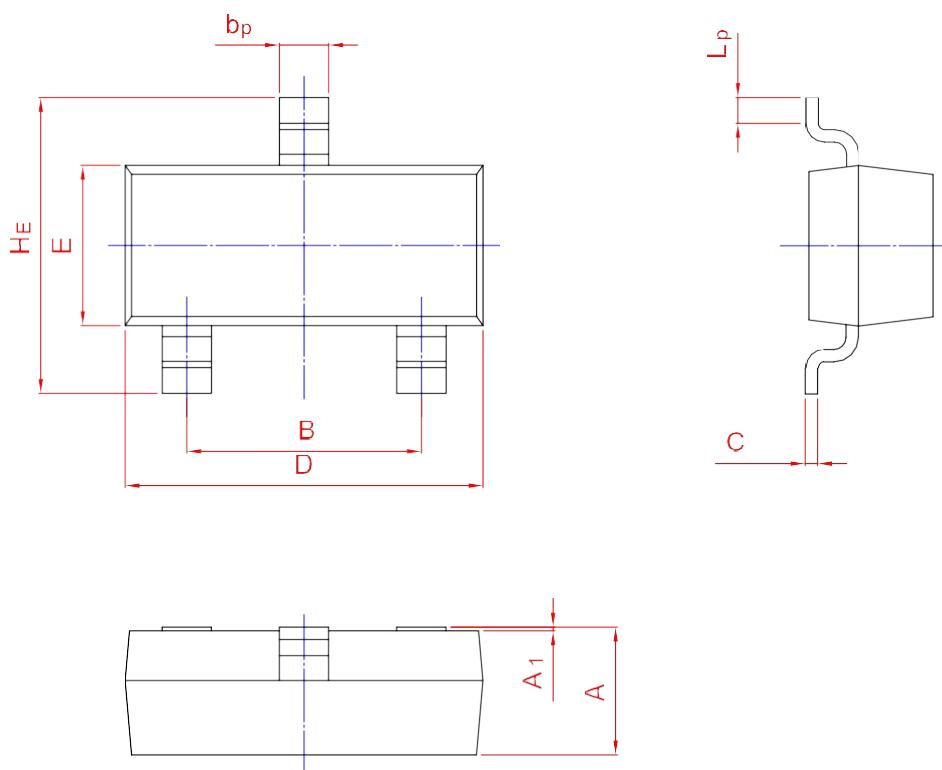


Fig. 4 Typical Collector Saturation Region

## PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



| UNIT | A            | B            | $b_p$        | C            | D            | $E$          | $H_E$        | $A_1$          | $L_p$        |
|------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|----------------|--------------|
| mm   | 1.40<br>0.95 | 2.04<br>1.78 | 0.50<br>0.35 | 0.19<br>0.08 | 3.10<br>2.70 | 1.65<br>1.20 | 3.00<br>2.20 | 0.100<br>0.013 | 0.50<br>0.20 |